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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Priority Application Serial No
Priority Filing Date December 31, 2001
nventor Ying Huang et al.
ssignee Micron Technology, Inc.
Priority Group Art Unit
<u>Priority</u> Examiner S.B. Geyer
Attorney's Docket No MI22-2347
itle: An Improved Method, Structure and Process Flow to Reduce Line-Line Capacitance
with Low-K Material

INFORMATION DISCLOSURE STATEMENT

References - - See attached Form PTO-1449

In compliance with 37 C.F.R. §§ 1.56, 1.97 and 1.98, your attention is directed to the United States patents and other references listed on the attached Form PTO-1449. No admission is made regarding whether all the submitted references are prior art.

The listed references were cited by, or submitted to, the Office in the parent, copending application of the above-identified application. The above-identified application is a continuation application of co-pending application Serial No. 10/039,456, filed December 31, 2001, upon which the above-identified application relies for a priority date under 35 U.S.C. §120. Such prior disclosure is sufficient for the above-identified application as far as copies of the references are concerned. 37 C.F.R. §1.98(d) and MPEP §609(2).

Citation of these references is respectfully requested.

Respectfully submitted,

Date: 7-23-03

D. Brent Kenady Reg. No. 40,045

U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE Priroity SERIAL NO. 10/039,456 ATTY. DOCKET NO. Form PTO-1449 M122-2347 APPLICANT LIST OF ART CITED BY APPLICANT Ying Huang et al. (Use several sheets if necessary) FILING DATE GROUP U.S. PATENT DOCUMENTS Class Subclass Filing Date *Examiner Document Date Name If Appropriate Initial Number 5,946,601 8/99 Wong et al. AA ΑB 6,033,979 3/00 Endo AC 6,037,664 3/00 Zhao et al. 6,046,104 4/00 ΑD Kepler 6,057,417 5/00 Arnold et al. ΑE ΑF 6,284,657 B1 09/01 Chooi et al. Sakai et al. AG 5,122,483 06/92 ΑH 6,265,779 B1 07/01 Grill et al. ΑI 6,410,437 B1 06/25/02 Flanner et al. ΑJ ΑK ΑL FOREIGN PATENT DOCUMENTS Class Subclass Translation Document Date Country Number Yes No AM AN ΑO ΑP AQ OTHER REFERENCES (including Author, Title, Date, Pertinent Pages, Etc.) AR Baliga, John, "Options for CVD of Dielectrics Include Low-k Materials," Semiconductor International June 1998, pp. 1-6 AS Singer, Peter, "Dual-Damascene Challenges Dielectric-Etch," Semiconductor International August 1999, pp. 1-5 ΑT **EXAMINER** DATE CONSIDERED

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.